

RF4E080BN

## Nch 30V 8A Middle Power MOSFET

## Datasheet

V <sub>DSS</sub>	30V
R <sub>DS(on)</sub> (Max.)	17.6mΩ
Ι <sub>D</sub>	±8A
P <sub>D</sub>	2.0W

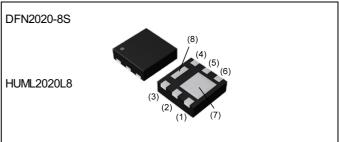
## Features

- 1) Low on resistance.
- 2) High Power small mold Package (HUML2020L8).
- 3) Pb-free lead plating ; RoHS compliant.
- 4) 100% Rg and UIS tested.
- 5) Halogen Free.

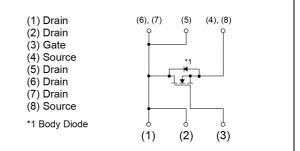
Application

Switching

#### Outline



#### Inner circuit



#### Packaging specifications

	Packing	Embossed Tape
	Reel size (mm)	180
Туре	Tape width (mm)	8
	Basic ordering unit (pcs)	3000
	Taping code	TR
	Marking	HB

#### • Absolute maximum ratings (T<sub>a</sub> = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain - Source voltage	V <sub>DSS</sub>	30	V
Continuous drain current	I <sub>D</sub>	±8	А
Pulsed drain current	I <sub>DP</sub> *1	±32	А
Gate - Source voltage	V <sub>GSS</sub>	±20	V
Avalanche current, single pulse	I <sub>AS</sub> *2	2.5	А
Avalanche energy, single pulse	E <sub>AS</sub> *2	4.6	mJ
Power dissipation	P <sub>D</sub> *3	2.0	W
Junction temperature	Tj	150	°C
Operating junction and storage temperature range	T <sub>stg</sub>	-55 to +150	C°

#### •Thermal resistance

Parameter	Sumbol	Values			Unit
Falameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - ambient	$R_{thJA}^{*3}$	-	-	62.5	°C/W

## • Electrical characteristics (T<sub>a</sub> = 25°C)

Deremeter	Currente e l	Canditiana	Values			Lincit	
Parameter	Symbol Conditions –		Min.	Тур.	Max.	Unit	
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 1mA	30	-	-	V	
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_j}$	I <sub>D</sub> = 1mA referenced to 25°C	-	21	-	mV/°C	
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V	-	-	1	μA	
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS}$ = ±20V, $V_{DS}$ = 0V	-	-	±100	nA	
Gate threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	1.0	-	2.0	V	
Gate threshold voltage temperature coefficient	$\frac{\Delta V_{GS(th)}}{\Delta T_j}$	I <sub>D</sub> = 1mA referenced to 25°C	-	-3	-	mV/°C	
Static drain - source	D *4	V <sub>GS</sub> = 10V, I <sub>D</sub> = 8A	-	13.5	17.6		
on - state resistance	R <sub>DS(on)</sub> *4	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 8A	-	18.9	24.6	mΩ	
Gate resistance	$R_{G}$	f=1MHz, open drain	-	2.8	-	Ω	
Forward Transfer Admittance	Y <sub>fs</sub>   <sup>*4</sup>	V <sub>DS</sub> = 5V, I <sub>D</sub> = 8A	5	-	-	S	

\*1 Pw $\leq$ 10µs, Duty cycle $\leq$ 1%

\*2 L  $\simeq$  1mH, V<sub>DD</sub> = 15V, R<sub>G</sub> = 25 $\Omega$ , Starting T<sub>j</sub> = 25°C Fig.3-1,3-2

\*3 Mounted on a Cu Board (40×40×0.8mm)

\*4 Pulsed



# • Electrical characteristics ( $T_a = 25^{\circ}C$ )

Parameter	Sumbol	Conditions	Values			Unit	
	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	660	-		
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 15V	-	90	-	pF	
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	75	-		
Turn - on delay time	$t_{d(on)}^{*4}$	$V_{DD} \simeq 15V, V_{GS} = 10V$	-	8	-		
Rise time	t <sub>r</sub> *4	I <sub>D</sub> = 4A	-	10	-	20	
Turn - off delay time	$t_{d(off)}$ *4	$R_L \simeq 3.75\Omega$	-	33	-	ns	
Fall time	t <sub>f</sub> *4	R <sub>G</sub> = 10Ω	-	7	-	[ 	

# • Gate charge characteristics ( $T_a = 25^{\circ}C$ )

Deremeter	Sumbol	Conditi	Conditions		Values		
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
Tatal gata abarga	O *4		V <sub>GS</sub> = 10V	-	14.5	-	
Total gate charge	Q <sub>g</sub> *4	V <sub>DD</sub> ≃ 15V		-	7.2	-	-0
Gate - Source charge	Q <sub>gs</sub> *4	I <sub>D</sub> = 8A	V <sub>GS</sub> = 4.5V	-	2.7	-	nC
Gate - Drain charge	Q <sub>gd</sub> <sup>*4</sup>			-	2.4	-	

# •Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Deremeter	Sumbol	Conditions	Values			l loit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Continuous forward current	I <sub>S</sub>	T - 25°0	-	-	1.67	А
Pulse forward current	I <sub>SP</sub> *1	T <sub>a</sub> = 25°C	-	-	32	А
Forward voltage	V <sub>SD</sub> <sup>*4</sup>	V <sub>GS</sub> = 0V, I <sub>S</sub> = 1.67A	-	-	1.2	V



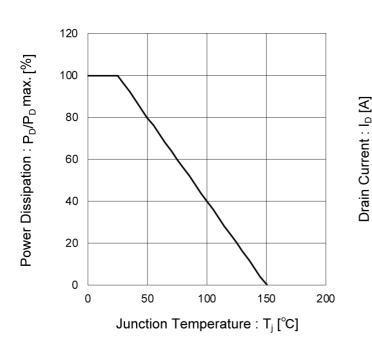
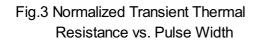
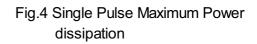


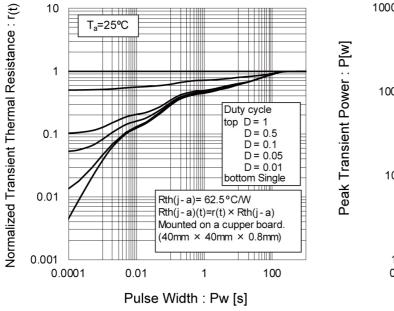
Fig.1 Power Dissipation Derating Curve

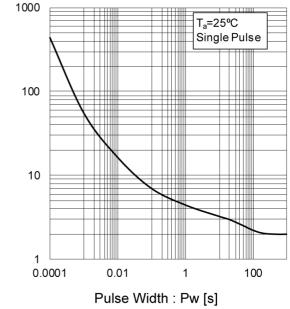
100 -------Pw = 100µs DC Operation P<sub>W</sub> = 1ms  $P_W = 10ms$ 10 1 Operation in this area is limited by R<sub>DS</sub>(on) (V<sub>GS</sub> = 10V) 0.1 T₂=25°C Single Pulse Mounted on a cupper board.  $(40\text{mm} \times 40\text{mm} \times 0.8\text{mm})$ 0.01 0.1 10 100 1 Drain - Source Voltage : V<sub>DS</sub> [V]

## Fig.2 Maximum Safe Operating Area











Drain Current : I<sub>D</sub> [A]

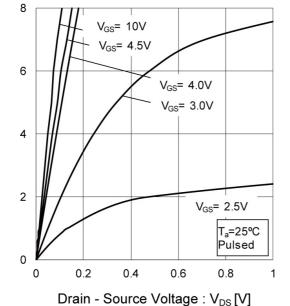
T<sub>a</sub>=25℃

Pulsed

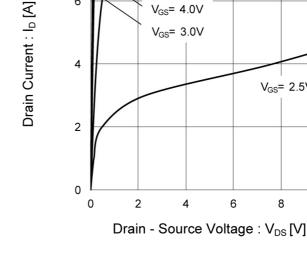
V<sub>GS</sub>= 2.5V

8

10



## Fig.5 Typical Output Characteristics(I)



8

6

4

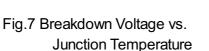
## Fig.6 Typical Output Characteristics(II)

V<sub>GS</sub>= 10V

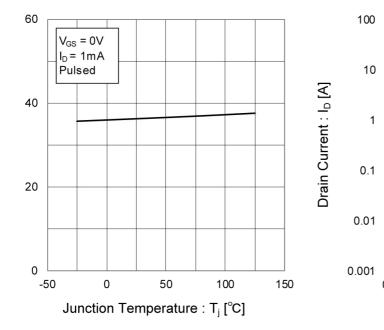
V<sub>GS</sub>= 4.5V

V<sub>GS</sub>= 4.0V

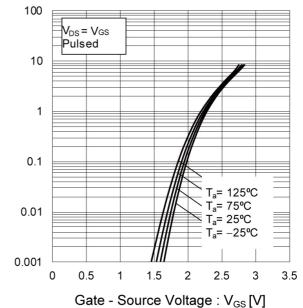
V<sub>GS</sub>= 3.0V



Drain - Source Breakdown Voltage : V<sub>(BR)DSS</sub> [V]



## Fig.8 Typical Transfer Characteristics





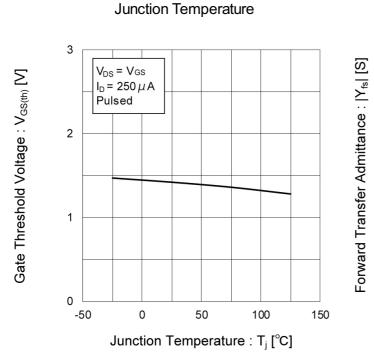


Fig.9 Gate Threshold Voltage vs.

## Fig.10 Forward Transfer Admittance vs. Drain Current

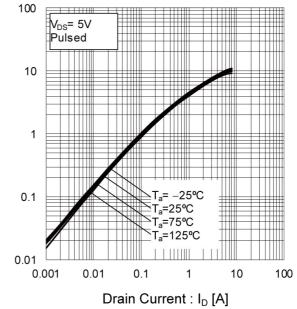
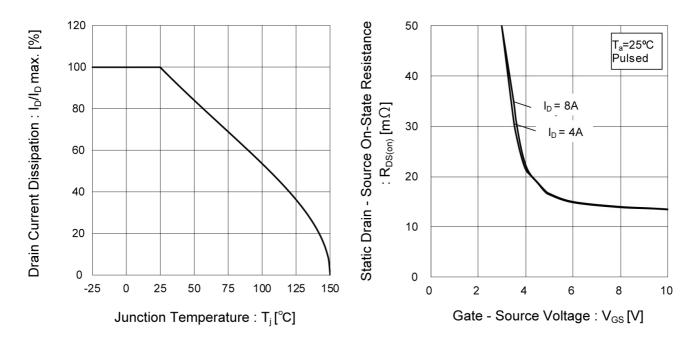


Fig.11 Drain Current Derating Curve

Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage





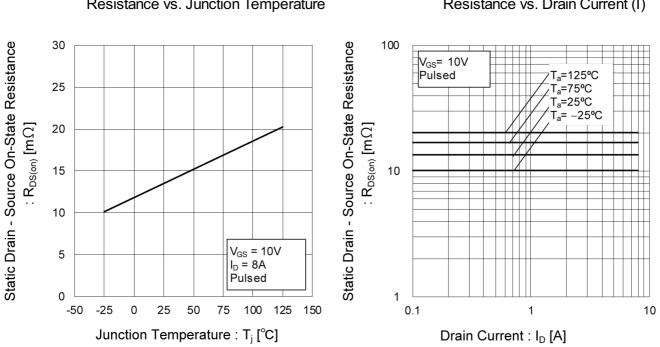
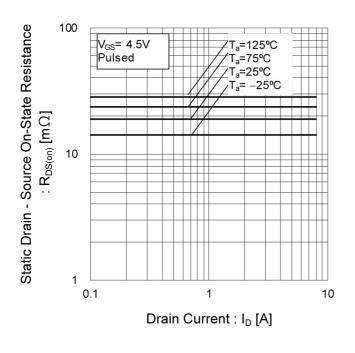


Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature Fig.14 Static Drain - Source On - State Resistance vs. Drain Current (I)

Fig.15 Static Drain - Source On - State Resistance vs. Drain Current (II)





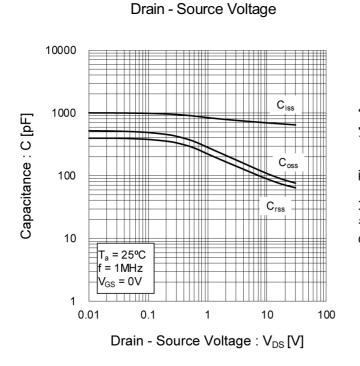


Fig.16 Typical Capacitance vs.

#### Fig.17 Switching Characteristics

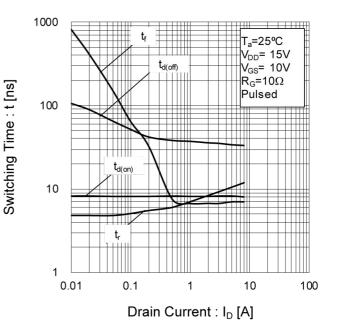


Fig.18 Dynamic Input Characteristics

Gate - Source Voltage : V<sub>GS</sub> [V]

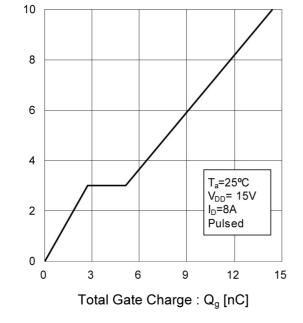
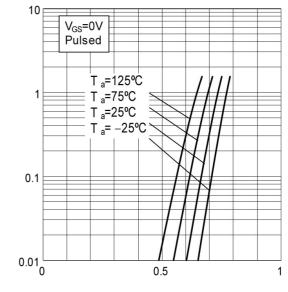


Fig.19 Source Current vs. Source Drain Voltage

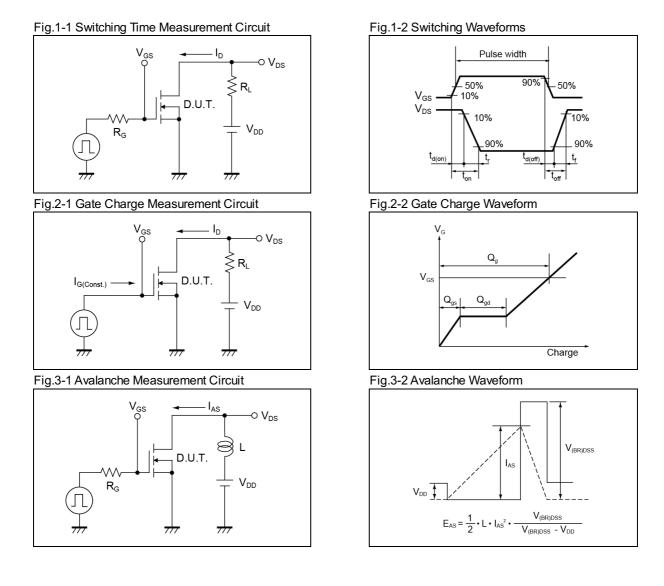


Source - Drain Voltage :  $V_{SD}$  [V]

Source Current : I<sub>s</sub> [A]



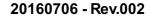
#### Measurement circuits



#### Notice

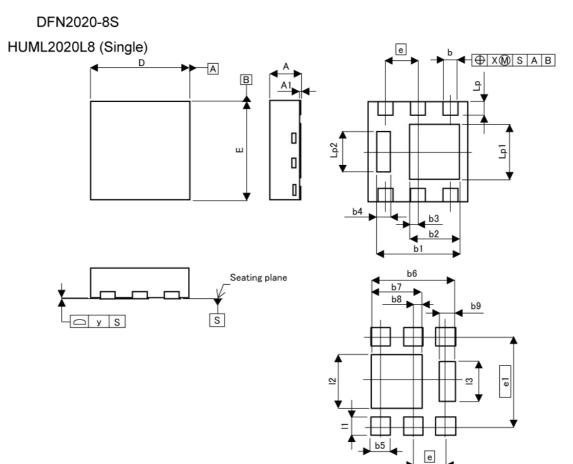
This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.





ROHM

#### Dimensions



Pattern of terminal position areas [Not a pattern of soldering pads]

DIM	MILIME	TERS	INCI	HES	
DIN	MIN	MAX	MIN	MAX	
А	0.55	0.65	0.022	0.026	
A1	0.00	0.05	0.000	0.002	
b	0.25	0.35	0.010	0.014	
b1	1.55	1.75	0.061	0.069	
b2	0.95	1.05	0.037	0.041	
b3	0.175		0.007		
b4	0.:	0.25		10	
D	1.90	2.10	0.075	0.083	
Е	1.90	2.10	0.075	0.083	
е	0.60	0.70	0.024	0.028	
Lp	0.225	0.325	0.009	0.013	
Lp1	1.00	1.20	0.039	0.047	
Lp2	0.	0.80		31	
х	-	0.10	-	0.004	
V	-	0.10	-	0.004	

DIM -	MILIMETERS		INC	HES	
	MIN	MAX	MIN	MAX	
b5	-	0.45	-	0.018	
b6	-	1.75	-	0.069	
b7	-	1.05	-	0.041	
b8	0.1	0.175		0.007	
b9	-	0.30	-	0.012	
e1	1.725		0.068		
1	-	0.425	-	0.017	
12	-	1.15	-	0.045	
13	-	0.85	-	0.033	

Dimension in mm/inches





# Notice

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(Note1) Medical Equipment Classification of the Specific Applications
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JÁPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASS II b	CLASSII
CLASSⅣ	CLASSII	CLASSⅢ	CLASSI

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
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  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

#### Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

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When disposing Products please dispose them properly using an authorized industry waste company.

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# RF4E080BN - Web Page

**Distribution Inventory** 

Part Number	RF4E080BN
Package	HUML2020L8(Single)
Unit Quantity	3000
Minimum Package Quantity	3000
Packing Type	Taping
Constitution Materials List	inquiry
RoHS	Yes